±5V to ±18V

0.05mV (typ)



LME49713

High Performance, High Fidelity Current Feedback Audio Operational Amplifier

General Description

The LME49713 is an ultra-low distortion, low noise, ultra high slew rate current feedback operational amplifier optimized and fully specified for high performance, high fidelity applications. Combining advanced leading-edge process technology with state-of-the-art circuit design, the LME49713 current feedback operational amplifier delivers superior signal amplification for outstanding performance. Operating on a wide supply range of ±5V to ±18V, the LME49713 combines extremely low voltage noise density (1.9nV/ $\sqrt{\text{Hz}}$) with very low THD+N (0.00036%) to easily satisfy the most demanding applications. To ensure that the most challenging loads are driven without compromise, the LME49713 has a high slew rate of ±1900V/µs and an output current capability of ±100mA. Further, dynamic range is maximized by an output stage that drives 150Ω loads to within 2.9V of either power supply voltage.

The LME49713's outstanding CMRR (88dB), PSRR (100dB), and $\rm V_{OS}$ (0.05mV) give the amplifier excellent operational amplifier DC performance.

The LME49713 is available in an 8-lead narrow body SOIC and 8-lead metal can (TO-99). Demonstration boards are available.

Key Specifications

■ Power Supply Voltage Range

■ THD+N, f = 1kHz $A_V = 1$, $R_L = 100\Omega$, $V_{OUT} = 3V_{RMS}$	0.0006% (typ)
■ THD+N, f = 1kHz $A_V = 1$, $R_L = 600\Omega$, $V_{OUT} = 1.4V_{RMS}$	0.00036% (typ)
■ Input Noise Density	1.9nV/ $\sqrt{\text{Hz}}$ (typ)
■ Slew Rate	±1900V/μs (typ)
■ Bandwidth $A_V = -1, R_L = 2k\Omega, R_F = 1.2k\Omega$	132MHz (typ)
■ Input Bias Current	1.8µA (typ)

Features

■ Easily drives 150Ω loads

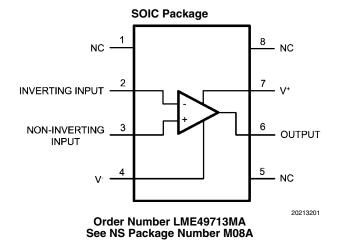
■ Input Offset Voltage

- Optimized for superior audio signal fidelity
- Output short circuit protection
- 100dB (typ) PSRR and 88dB (typ) CMRR
- SOIC High Performance and Metal can packages

Applications

- Ultra high quality audio amplification
- High fidelity preamplifiers
- High fidelity multimedia
- State of the art phono pre amps
- High performance professional audio
- High fidelity equalization and crossover networks
- High performance line drivers
- High performance line receivers
- High fidelity active filters

Connection Diagrams



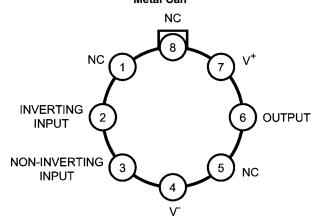
LME49713MA Top Mark

NZXTT L49713 MA

N = National Logo
Z = Assembly plant code
X = 1 Digit date code
TT = Die traceability
L49713 = LME49713 MA = Package code

20213222

Metal Can



Order Number LME49713HA See NS Package Number H08C

2

Absolute Maximum Ratings (Note 1, Note

2

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Power Dissipation	Internally Limited
ESD Rating (Note 4)	2000V
ESD Rating (Note 5)	200V
Junction Temperature	150°C
Thermal Resistance	
θ_{JA} (MA)	145°C/W
Temperature Range	
$T_{MIN} \le T_A \le T_{MAX}$	$-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 70^{\circ}\text{C}$
Supply Voltage Range	$\pm 5.0 \text{V} \le \text{V}_{\text{S}} \le \pm 18 \text{V}$

			LME49713		T
Symbol	Parameter	Conditions	Typical Limit		Units (Limits)
			(Note 6)	(Note 7)	(Limits)
		$A_V = 1$, $V_{OUT} = 3V_{RMS}$, $R_F = 1.2k\Omega$			
THD+N	Total Harmonic Distortion + Noise	$R_L = 100\Omega$, $V_{OUT} = 3V_{RMS}$	0.0006	0.00071	% (max)
		$R_L = 600\Omega$, $V_{OUT} = 1.4V_{RMS}$	0.00036	0.00045	% (max)
IMD	Intermodulation Distortion	$A_V = 1$, $V_{IN} = 3V_{RMS}$ Two-tone, 60Hz & 7kHz 4:1	0.00009		%
BW	Bandwidth	$A_V = -1$, $R_F = 1.2k\Omega$	132		MHz
SR	Slew Rate	$V_{O} = 20V_{P-P}, A_{V} = -1$	±1900		V/µs
FPBW	Full Power Bandwidth	$V_{OUT} = 20V_{P-P}, A_V = -1$	30		MHz
t _s	Settling time	$A_V = -1$, 10V step, 0.1% error range	50		ns
•	Equivalent Input Noise Voltage	$f_{BW} = 20$ Hz to 20kHz	0.26	0.6	μV _{RMS} (max)
e _n	Equivalent Input Noise Density	f = 1kHz f = 10Hz	1.9 11.5	4.0	nV/√ Hz (max)
i _n	Current Noise Density	f = 1kHz f = 10Hz	16 160		pAJ√Hz
V _{os}	Input Offset Voltage		±0.05	±1.0	mV (max)
ΔV _{OS} /ΔTemp	Average Input Offset Voltage Drift vs Temperature	-40°C ≤ T _A ≤ 85°C	0.29		μV/°C
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	$V_{SUPPLY} = \pm 5V \text{ to } \pm 15V$ (Note 8)	100	95	dB (min)
I _B	Input Bias Current	V _{CM} = 0V	1.8	6	μA (max)
ΔI _{OS} /ΔTemp	Input Bias Current Drift vs Temperature	-40°C ≤ T _A ≤ 85°C Inverting input Non-inverting input	4.5 4.7		nA/°C nA/°C
I _{os}	Input Offset Current	V _{CM} = 0V	1.3	5	μA (max)
V _{IN-CM}	Common-Mode Input Voltage Range		±13.5	(V+) - 2.0 (V-) + 2.0	V (min) V (min)
CMRR	Common-Mode Rejection	-10V <vcm<10v< td=""><td>88</td><td>86</td><td>dB (min)</td></vcm<10v<>	88	86	dB (min)
Z _{IN}	Non-inverting-input Input Impedance	-10V <vcm<10v< td=""><td>1.2</td><td></td><td>MΩ</td></vcm<10v<>	1.2		MΩ
Z _{IN}	Inverting-input Input Impedance	-10V <vcm<10v< td=""><td>58</td><td></td><td>Ω</td></vcm<10v<>	58		Ω
Z _T	Transimpedance	$V_{OUT} = \pm 10V$ $R_L = 200\Omega$ $R_L = \infty$	4.2 4.7	2.0 2.65	MΩ (min) MΩ (min)
V		$R_L = 150\Omega$	±11.1	±10.3	V (min)
V_{OUTMAX}	Maximum Output Voltage Swing	$R_1 = 600\Omega$	±11.6	±11.4	V (min)

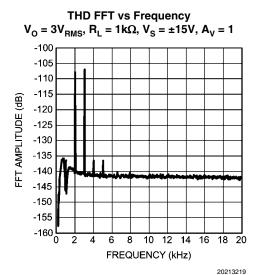
			LME49713		
Symbol	Parameter	Conditions	Typical	Limit	Units (Limits)
	!		(Note 6)	(Note 7)	(Lillins)
I _{OUT}	Output Current	$R_L = 150\Omega, V_S = \pm 18V$	±100	±91	mA (min)
I _{OUT-CC}	Instantaneous Short Circuit Current		±140		mA
R _{OUT}	Output Resistance	f _{IN} = 5MHz, Open-Loop	10		Ω
I _s	Total Quiescent Current	I _{OUT} = 0mA	8.5	10	mA (max)

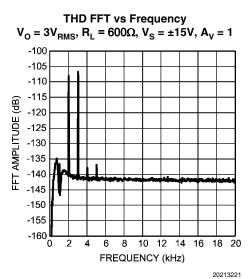
Note 1: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.

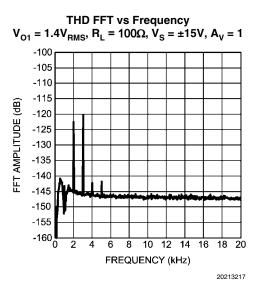
Note 2: The Electrical Characteristics tables list guaranteed specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not guaranteed.

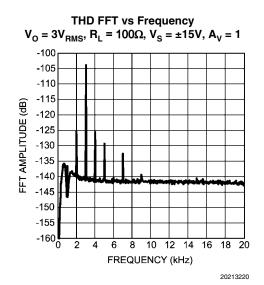
- Note 3: Amplifier output connected to GND, any number of amplifiers within a package.
- Note 4: Human body model, applicable std. JESD22-A114C.
- Note 5: Machine model, applicable std. JESD22-A115-A.
- Note 6: Typical values represent most likely parametric norms at $T_A = +25^{\circ}C$, and at the *Recommended Operation Conditions* at the time of product characterization and are not guaranteed.
- Note 7: Datasheet min/max specification limits are guaranteed by test or statistical analysis.
- Note 8: PSRR is measured as follows: V_{OS} is measured at two supply voltages, $\pm 5V$ and $\pm 15V$. PSRR = $|\ 20log(\Delta V_{OS}/\Delta V_S)|$ |.

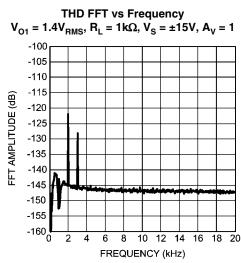
Typical Performance Characteristics

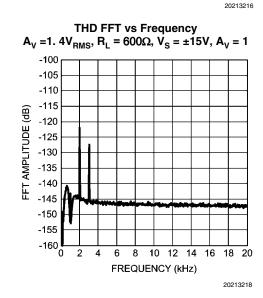


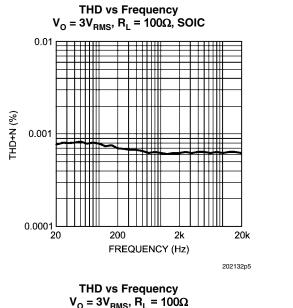


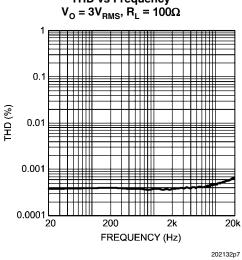


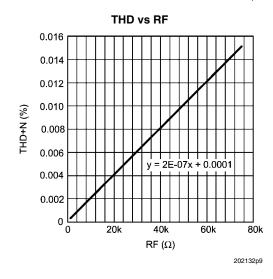


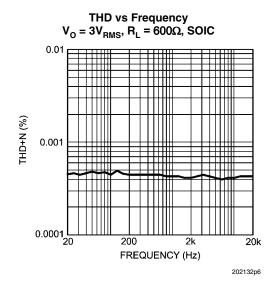


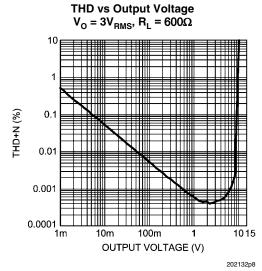


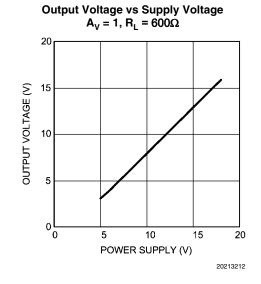




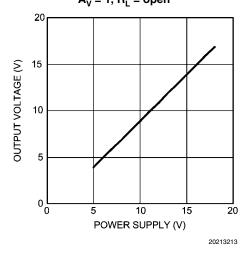




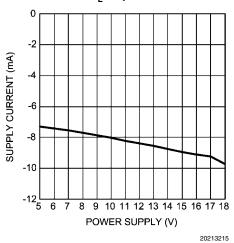




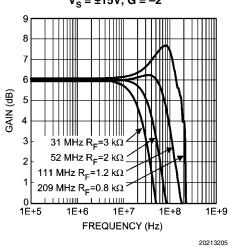
Output Voltage vs Supply Voltage $A_V = 1$, $R_L = open$



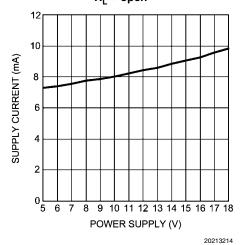
Supply Current (I_{EE}) vs Power Supply R_L = open



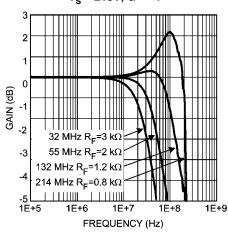
Gain vs Frequency $V_S = \pm 15V$, G = -2



Supply Current (I_{CC}) vs Power Supply R_L = open

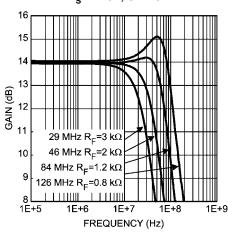


Gain vs Frequency $V_S = \pm 15V$, G = -1

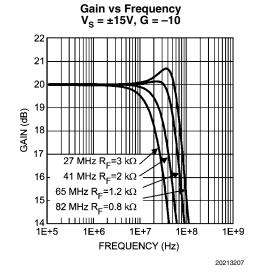


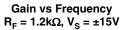
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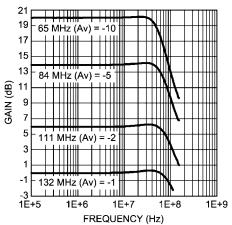
Gain vs Frequency $V_S = \pm 15V$, G = -5



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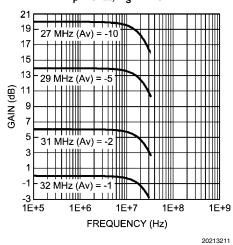




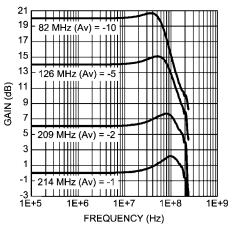
Gain vs Frequency $R_F = 3k\Omega$, $V_S = \pm 15V$

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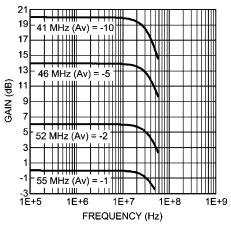


Gain vs Frequency $R_F = 800\Omega$, $V_S = \pm 15V$



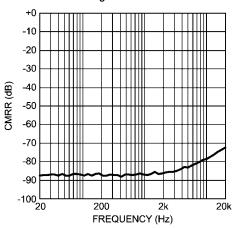
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Gain vs Frequency $R_F = 2k\Omega$, $V_S = \pm 15V$

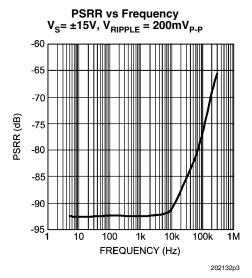


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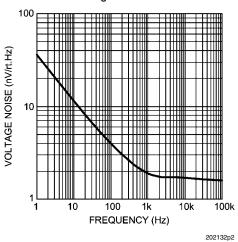
CMRR vs Frequency $V_S = \pm 15V$



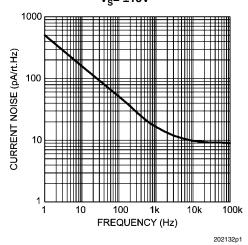
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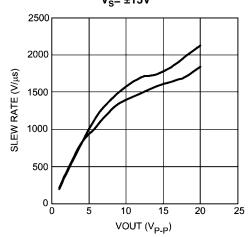
Equivalent Voltage Noise vs Frequency V_S = ±15V



Current Noise vs Frequency V_S= ±15V



Slew Rate vs Output Voltage V_S = ±15V



202132p4

Application Information

GENERAL AMPLIFIER FUNCTION

Voltage feedback amplifiers have a small-signal bandwidth that is a function of the closed-loop gain. Conversely, the LME49713 current feedback amplifier features a small-signal bandwidth that is relatively independent of the closed-loop gain. This is shown in Figure 1 where the LME49713's gain is $-1,-2,\,-5$ and -10. Like all current feedback amplifiers, the LME49713's closed-loop bandwidth is a function of the feedback resistance value. Therefore, $\rm R_{\rm s}$ must be varied to select the desired closed-loop gain.

POWER SUPPLY BYPASSING AND LAYOUT CONSIDERATIONS

Properly placed and correctly valued supply bypassing is essential for optimized high-speed amplifier operation. The supply bypassing must maintain a wideband, low-impedance capacitive connection between the amplifier's supply pin and ground. This helps preserve high speed signal and fast transient fidelity. The bypassing is easily accomplished using a parallel combination of a $10\mu F$ tantalum and a $0.1\mu F$ ceramic capacitors for each power supply pin. The bypass capacitors should be placed as close to the amplifier power supply pins as possible.

FEEDBACK RESISTOR SELECTION (R_f)

The value of the $R_{\rm f}$, is also a dominant factor in compensating the LME49713. For general applications, the LME49713 will maintain specified performance with an $1.2k\Omega$ feedback resistor. Although this value will provide good results for most applications, it may be advantageous to adjust this value slightly for best pulse response optimized for the desired bandwidth. In addition to reducing bandwidth, increasing the feedback resistor value also reduces overshoot in the time domain response.

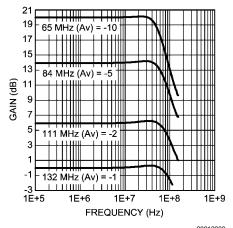


FIGURE 1. Bandwidth as a function of gain

SLEW RATE CONSIDERATIONS

A current feedback amplifier's slew rate characteristics are different than that of voltage feedback amplifiers. A voltage feedback amplifier's slew rate limiting or non-linear amplifier behavior is dominated by the finite availability of the first stage tail current charging the second stage voltage amplifier's compensation capacitor. Conversely, a current feedback amplifier's slew rate is not constant. Transient current at the inverting input determines slew rate for both inverting and non-inverting gains. The non-inverting configuration slew rate is also determined by input stage limitations. Accordingly, variations of slew rates occur for different circuit topologies.

DRIVING CAPACITIVE LOADS

The LME49713 can drive significantly higher capacitive loads than many current feedback amplifiers. Although the LME49713 can directly drive as much as 100pF without oscillating, the resulting response will be a function of the feedback resistor value.

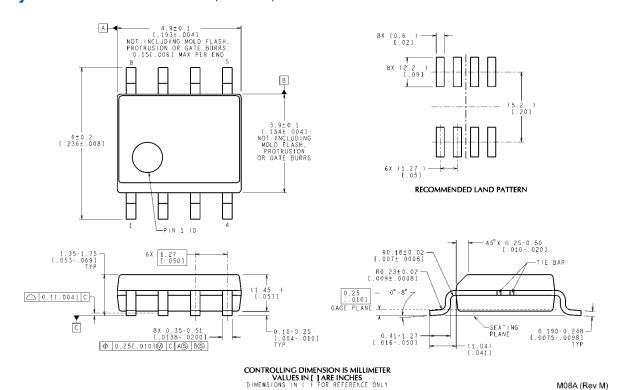
CAPACITIVE FEEDBACK

It is quite common to place a small lead-compensation capacitor in parallel with a voltage feedback amplifier's feedback resistance, $R_{\rm f}$. This compensation reduces the amplifier's peaking in the frequency domain and damps the transient response. Whereas this yields the expected results when used with voltage feedback amplifiers, this technique must not be used with current feedback amplifiers. The dynamic impedance of capacitors in the feedback loop reduces the amplifier's stability. Instead, reduced peaking in the frequency response and bandwidth limiting can be accomplished by adding an RC circuit to the amplifier's input.

Revision History

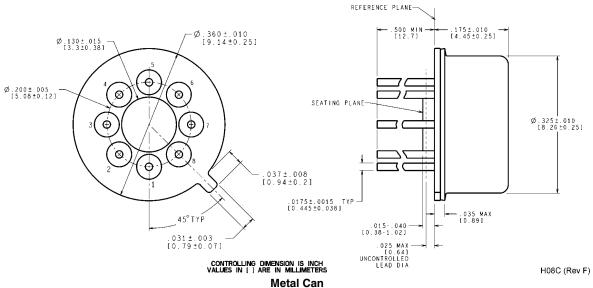
Rev	Date	Description	
1.0	09/26/07	Initial release.	
1.1	09/28/07	Added the Typical Performance curves.	
1.2	10/03/07	Input Limit values.	
1.3	10/29/07	Edited the Specification table, typical performance curve, and text edits.	
1.4	01/29/08	Added more curves in the Typical Performance section.	
1.5	07/24/08	Added the Metal Can package.	
1.6	08/20/08	Text edits (updated some of the curves' titles).	
1.7	08/22/08	Text edits.	
1.8	02/08/10	Input changes on typical and limits in the EC table.	
1.9	04/23/10	Input Typical and Limit edits on THD+N and I _{OUT} in the EC table.	
2.0	06/02/10	Input text edits on the first page.	

Physical Dimensions inches (millimeters) unless otherwise noted

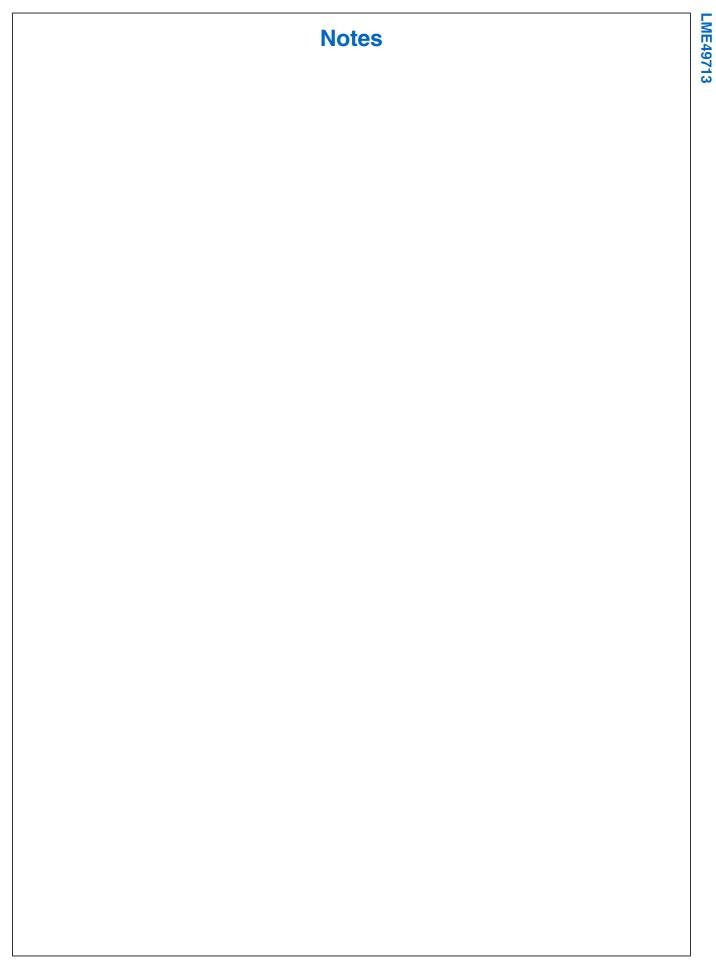


M08A (Rev M)

SOIC Package Order Number LME49713MA **NS Package Number M08A**



Order Number LME49713HA NS Package Number H08C



Notes

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